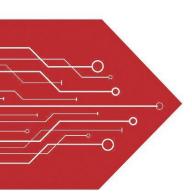
MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Broduct data speet





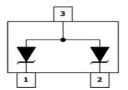


Features

- $300 \text{ Watts peak pulse power (tp = } 8/20 \mu \text{s})$
- Transient protection for high speed data lines to IEC 61000-4-2 (ESD) ±30kV (air), ±30kV (contact) IEC 61000-4-4 (EFT) 40A (5/50ns)
- Working voltages: 3V,5V,12V,15V,24V
- Protects two bidirectional line
- Low operating and clamping voltages
- Solid-state silicon avalanche technology

Applications

- Notebooks, Desktops, Servers and Video Graphics Cards
- **USB Power & Data Line Protection**
- Monitors and Flat Panel Displays
- I²C Bus Protection
- Portable Instrumentation
- Set Top Box





SOT-23

Maximum Rating @ Ta=25°Cunless otherwisespecified

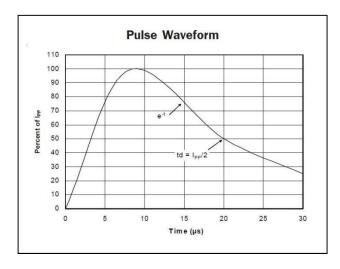
Symbol	Parameter	Ratings	Units
P _{PK}	Peak Pulse Power (tp = 8/20μs)	300	Watts
TL	Lead Soldering Temperature	260(10sec.)	$^{\circ}$
TJ	Operating Temperature	-55 to +125	°C
T _{STG}	Storage Temperature	-55 to +150	°C

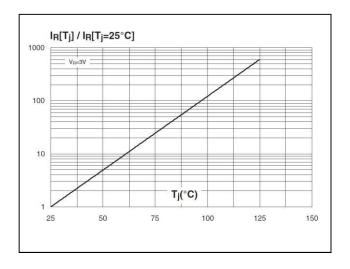
Electrical Characteristics@ Ta=25°Cunless otherwise

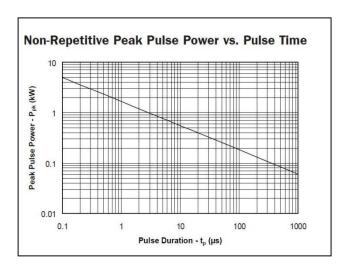
	V_{RWM}	V _B	Ι _Τ	V _C @1A	V	С	I _R	Ст
P/N	(V)	(V)	(mA)	(V)	(\	/)	(µA)	(pF)
	(max.)	(min.)		(max.)	(max.)	(@A)	(max.)	(max.)
ESD3V3S2UT-MS	3.3	4	1	7.0	14	20	40	450
ESD5V2S2UT-MS	5	6	1	9.8	18	17	10	300
ESD12VS2UT-MS	12	13.3	1	19	32	11	1	130
ESD15VS2UT-MS	15	16.7	1	24	38	10	1	120
ESD24VS2UT-MS	24	26.7	1	43	52	7	1	80

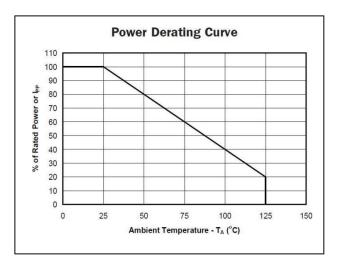


Typical Characteristics@ Ta=25°Cunless otherwise specified



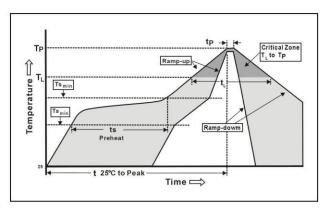






Soldering Parameters

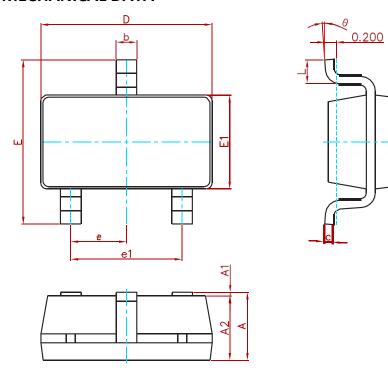
Reflow Condition		Fb – Free assembly	
	- Temperature Min (T _{s(Min)})	150°C	
Pre Heat	- Temperature Max (T _{s(Max)})	200°C	
	-Time (Min to max) (t _s)	60 - 180 secs	
Average ramp up rate (Liquidus) Temp (T _L) to peak		3°C/second Max	
T _{s (Max)} to T	- Ramp-up Rate	3°C/second Max	
Reflow	-Temperature (T _L) (Liquidus)	217°C	
	-Temperature (t _L)	60 - 150 seconds	
Peak Temperature (T _p)		250+0/-5 °C	
Time within 5°C of actual peak Temperature (t _p)		20 – 40 seconds	
Ramp-dowm Rate		6°C/second Max	
Time 25°C to peak Temperature (T _p)		8 minutes Max.	
Do not exceed		260°C	





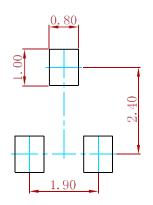
Semiconductor

PACKAGE MECHANICAL DATA



Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E1	1.500	1.700	0.059	0.067	
E	2.650	2.950	0.104	0.116	
е	0.950(BSC)		0.037(BSC)		
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
0	0°	8°	0°	8°	

Suggested Pad Layout



- 1.Controlling dimension:in millimeters.
 2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
ESDXXXS2UT-MS	SOT-23	3000



Compiance

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